

MAY 09 2005

P910351

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Hsu et al.

U.S. Serial No: 10/627,000

Filed: July 25, 2003


For: METHOD FOR FORMING NON-
VOLATILE MEMORY CELL WITH
LOW-TEMPERATURE-FORMED
DIELECTRIC BETWEEN WORD AND
BIT LINES, AND NON-VOLATILE
MEMORY ARRAY INCLUDING SUCH
MEMORY CELLS

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/ Examiner: Schillinger, Laura M.
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/ Group Art: 2813
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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

CERTIFICATE OF FACSIMILE TRANSMISSION
I hereby certify that this paper is being facsimile
transmitted to: Commissioner for Patents at fax number 703-872-
9306 on May 9, 2005.


Kenton R. Mullins, Reg. No. 36,331


TRANSMITTAL

Sir:

Submitted herewith are

- ~ Amendment (8 pages including this Transmittal); and
- ~ The Commissioner is hereby authorized to charge any needed fees to deposit account 50-1600.

Respectfully submitted,


Kenton R. Mullins
Attorney for Applicants
Registration No. 36,331

May 9, 2005
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AMENDMENT

Dear Sir:

In response to the Office Action mailed February 8, 2005, Applicants respectfully request that the following amendments be entered in the above-identified patent application:

Amendments to the Claims are reflected in the listing of claims, which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.